High Voltage PNP Silicon Plastic Power Transistors

These devices are designed for line operated audio output amplifier, SWITCHMODE power supply drivers and other switching applications.

Features

- 300 V to 400 V (Min) V_{CEO(sus)}
- 1.0 A Rated Collector Current
- Popular TO-220 Plastic Package
- PNP Complements to the TIP47 thru TIP50 Series
- Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage MJE5730 MJE5731 MJE5731A	V _{CEO}	300 350 375	Vdc
Collector–Base Voltage MJE5730 MJE5731 MJE5731A	V _{CB}	300 350 375	Vdc
Emitter-Base Voltage	V _{EB}	5.0	Vdc
Collector Current – Continuous – Peak	I _C I _{CM}	1.0 3.0	Adc
Base Current	Ι _Β	1.0	Adc
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	40 0.32	W W/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	2.0 0.016	W W/°C
Unclamped Inducting Load Energy (See Figure 10)	E	20	mJ
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	3.125	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	62.5	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



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1.0 AMPERE
POWER TRANSISTORS
PCP SILICON
300-350-400 VOLTS
50 WATTS



TO-220AB CASE 221A-09 STYLE 1

MARKING DIAGRAM



MJE573x = Device Code

x = 0, 1, or 1A

G = Pb-Free Package A = Assembly Location

Y = Year WW = Work Week

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

bol Min	n Max	Unit
•	•	1
300 350 375) –	Vdc
EO –	1.0 1.0 1.0	mAdc
=S - - -	1.0 1.0 1.0	mAdc
30 -	1.0	mAdc
	•	
E 30		-
(sat) -	1.0	Vdc
(on) –	1.5	Vdc
•	•	-
10	_	MHz
e 25	_	_

^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

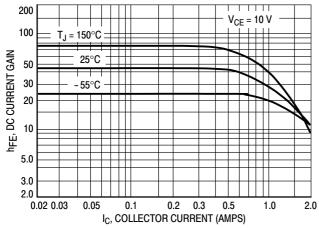
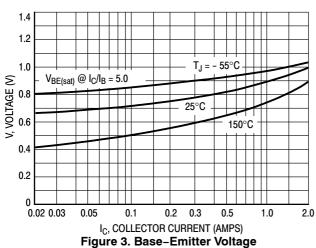
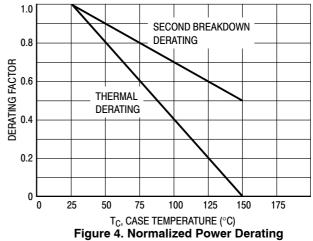


Figure 1. DC Current Gain



 $T_J = 25^{\circ}C$ 150°C $V_{CE(sat)}$ @ $I_C/I_B = 5.0$ 0.02 0.03 0.05 0.2 0.3 2.0 IC, COLLECTOR CURRENT (AMPS)

Figure 2. Collector-Emitter Saturation Voltage



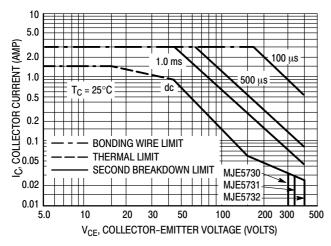


Figure 5. Forward Bias Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate I_C – V_{CE} limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 5 is based on $T_{J(pk)} = 150^{\circ}\text{C}$; T_{C} is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^{\circ}\text{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 6. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

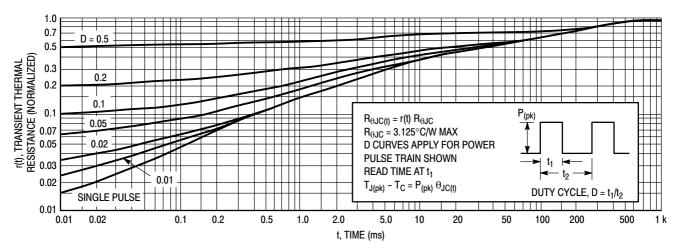


Figure 6. Thermal Response

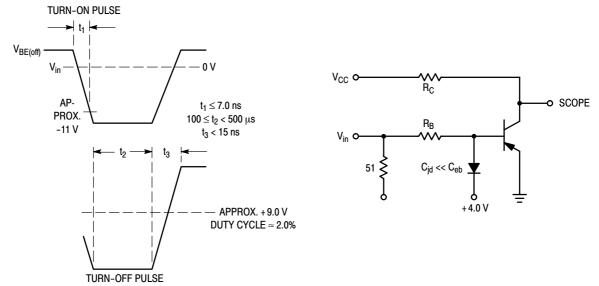
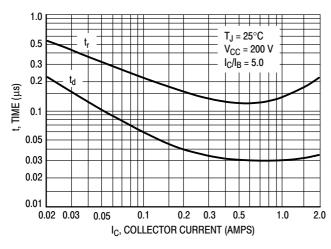


Figure 7. Switching Time Equivalent Circuit

5.0

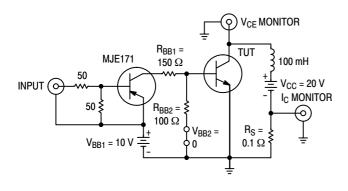


 $T_J = 25^{\circ}C$ 3.0 V_{CC} = 200 V 2.0 $I_{\rm C}/I_{\rm B} = 5.0$ 1.0 t, TIME (µs) 0.5 0.3 0.2 0.1 0.05 0.02 0.03 0.3 1.0 2.0 0.05 0.1 0.2 0.5 IC, COLLECTOR CURRENT (AMPS)

Figure 8. Turn-On Resistive Switching Times

Figure 9. Resistive Turn-Off Switching Times

Test Circuit



Voltage and Current Waveforms

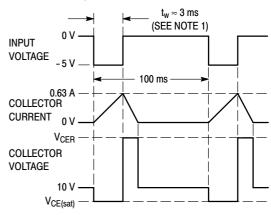


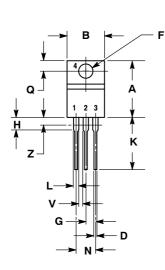
Figure 10. Inductive Load Switching

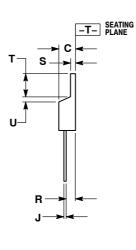
ORDERING INFORMATION

Device	Package	Shipping
MJE5730	TO-220	
MJE5730G	TO-220 (Pb-Free)	
MJE5731	TO-220	
MJE5731G	TO-220 (Pb-Free)	50 Units / Rail
MJE5731A	TO-220	
MJE5731AG	TO-220 (Pb-Free)	

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 ISSUE AG





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
 Y14.5M. 1982.
- 2. CONTROLLING DIMENSION: INCH.
- DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INC	INCHES MILLIMETERS		IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.036	0.64	0.91
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
Н	0.110	0.161	2.80	4.10
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

STYLE 1:

IN 1. BASE

- 2. COLLECTOR
- . EMITTER
- 4. COLLECTOR

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